

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L6	1	US-4573119-\$.did.	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/18 09:58
L7	1	EP-1050887-A1.did.	US-PGPUB; USPAT; USOCR; EPO	OR	ON	2008/09/18 10:01
S1	0	"10539164".ap.	DERWENT	OR	OFF	2008/09/16 10:08
S2	1	US-20060126422-\$.did.	DERWENT	OR	OFF	2008/09/16 10:14
S3	27621	(memory near2 card) SIM	DERWENT	OR	OFF	2008/09/16 10:26
S4	1	S3 and (temper-resistant)	DERWENT	OR	OFF	2008/09/16 10:26
S5	7	S3 and (tamper-resistant)	DERWENT	OR	OFF	2008/09/16 10:26
S6	49	(US-5497411-\$ or US-5923759-\$ or US-6230267-\$ or US-5533123-\$ or US-5742756-\$ or US-5914471-\$ or US-5936221-\$ or US-6005942-\$ or US-6006988-\$ or US-6059586-\$ or US-6092202-\$ or US-4529870-\$ or US-4629871-\$ or US-4809185-\$ or US-4933971-\$ or US-5012074-\$ or US-5179871-\$ or US-5203218-\$ or US-5237609-\$ or US-5239166-\$ or US-5239926-\$ or US-5282247-\$ or US-5293424-\$ or US-5436621-\$ or US-5442704-\$ or US-5470241-\$).did. or (US-5476387-\$ or US-5491827-\$ or US-5504817-\$ or US-5505628-\$ or US-5517375-\$ or US-5555490-\$ or US-5563400-\$ or US-5605334-\$ or US-5648647-\$ or US-5735525-\$ or US-5737185-\$ or US-5805702-\$ or US-5818030-\$ or US-5820391-\$ or US-5841866-\$ or US-5848401-\$ or US-5856659-\$ or US-5877941-\$ or US-5882230-\$ or US-5923884-\$ or US-6093103-\$ or US-6105013-\$ or US-6134628-\$).did.	USPAT	OR	OFF	2008/09/16 14:30

S7	49	S6 and @ad<"20021216"	USPAT	OR	OFF	2008/09/16 14:31
S8	147711	(memory smart plastic IC) near3 card	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 14:57
S9	56021	S8 and (first second divided) near3 (memory portion section part)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 14:58
S10	65249	S8 and (first second divided secure) near3 (memory portion section part area)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 14:59
S11	919	S10 and (tamper attack intrusion) near3 (resistance protection)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 15:00
S12	358	S11 and @ad<"20021216"	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 15:01
S13	28391	S8 and (first second divided secure) near3 (memory portion section part area) with memory	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 15:02
S14	573	S13 and (tamper attack intrusion) near3 (resistance protection)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 15:02
S15	228	S14 and @ad<"20021216"	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 15:02
S16	0	WO-0069204-\$.did.	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 15:25
S17	0	WO-00069204-\$.did.	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 15:25
S18	11	("5724423"   "5757918"   "5842124"   "5875404"   "5907804"   "6012634"   "6085081"   "6179205"   "6314519"   "6367011"   "6480725").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/09/16 15:25
S19	0	("6975883").URPN.	USPAT	OR	OFF	2008/09/16 15:26
S20	1	WO-0069204-\$.did.	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2008/09/16 15:31
S21	1	2001-024920.NRAN.	DERWENT	OR	OFF	2008/09/16 15:31
S22	1	US-5724423-A\$.did.	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 15:35
S23	1	JP-200114441-\$.did. JP-2002229861-\$.did.	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2008/09/16 15:37

S24	122911	(memory smart plastic IC semiconductor) adj card	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 17:06
S25	162470	(secure private protected) near3 (area portion partition sector part memory)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 17:13
S26	1153717	((control processing logic) adj unit) processor	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 17:15
S27	8619	S24 and S25 and S26	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 17:15
S28	11115	S24 and S25	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 17:15
S29	43039	(memory smart plastic IC semiconductor) adj card	DERWENT	OR	ON	2008/09/16 17:18
S30	26145	(secure private protected) near3 (area portion partition sector part memory)	DERWENT	OR	ON	2008/09/16 17:18
S31	681262	((control processing logic) adj unit) processor	DERWENT	OR	ON	2008/09/16 17:19
S32	182	S29 and S30 and S31	DERWENT	OR	ON	2008/09/16 17:19
S33	392	S24 same S25 same S26	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 17:20
S34	3203	S24 same S25	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 17:20
S35	39	S32 and @ad<"20021216"	DERWENT	OR	ON	2008/09/16 17:20
S37	962	S34 and @ad<"20021216"	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/16 17:21
S38	122911	(memory smart plastic IC semiconductor) adj card	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 10:58
S39	162470	(secure private protected) near3 (area portion partition sector part memory)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 10:58
S40	1153717	((control processing logic) adj unit) processor	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 10:58
S41	392	S38 same S39 same S40	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 10:58
S42	133	S41 and @ad<"20021216"	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 10:58
S43	599	(TAKAGI near1 YOSHIHIKO).in. (NAKANIISHI near1 YOSHIAKI).in. (SAKAKI near1 OSAMU)". in. "(KIKUCHI near1 TAKAFUMI).in.	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 11:38

S44	36191	(MATSUSHITA and ELECTRIC and INDUSTRIAL).as.	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 11:38
S45	19	S43 and S44	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 11:38
S46	43039	(memory smart plastic IC semiconductor) adj card	DERWENT	OR	ON	2008/09/17 11:38
S47	26145	(secure private protected) near3 (area portion partition sector part memory)	DERWENT	OR	ON	2008/09/17 11:38
S48	681262	((control processing logic) adj unit) processor	DERWENT	OR	ON	2008/09/17 11:38
S49	182	S46 and S47 and S48	DERWENT	OR	ON	2008/09/17 11:38
S50	0	S45 and S49	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 11:38
S51	1	S45 and ((first adj memory) near3 non-tamper-resistance near3 (usual adj area))	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 11:40
S52	32	(US-20020154767-\$ or US-20040003262-\$ or US-20030194086-\$ or US-20020184149-\$ or US-20030041253-\$).did. or (US-6006988-\$ or US-5856659-\$ or US-5914471-\$ or US-5818030-\$ or US-5504817-\$ or US-5841866-\$ or US-5491827-\$ or US-5442704-\$ or US-5293424-\$ or US-5237609-\$ or US-7236455-\$ or US-6424717-\$ or US-6408075-\$ or US-6839847-\$ or US-5745571-\$ or US-6038551-\$ or US-6901385-\$ or US-5623637-\$ or US-4985921-\$).did. or (WO-2004055680-\$ or WO-2004032557-\$ or US-20030114144-\$ or WO-0069204-\$ or JP-2002229861-\$ or WO-0065602-\$ or EP-1043860-\$ or EP-923056-\$).did.	US-PGPUB; USPAT; DERWENT	OR	OFF	2008/09/17 14:53
S53	22	S52 and (encryption encrypted hash\$3)	US-PGPUB; USPAT; DERWENT	OR	OFF	2008/09/17 14:56
S54	9	S52 and ((encryption encrypted) and hash\$3)	US-PGPUB; USPAT; DERWENT	OR	OFF	2008/09/17 15:07

S55	122911	(memory smart plastic IC semiconductor) adj card	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 15:59
S56	162470	(secure private protected) near3 (area portion partition sector part memory)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 15:59
S57	1153717	((control processing logic) adj unit) processor	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 15:59
S58	392	S55 same S56 same S57	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 15:59
S59	133	S58 and @ad<"20021216"	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 15:59
S60	30	S59 and (encrypt\$3 and hash)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 15:59
S61	15	S60 and ((encrypt\$3 same stor\$3) with data)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 16:00
S62	10	S60 and ((encrypt\$3 same stor\$3) near3 data)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 16:04
S63	0	S52 and ((address near3 table) and boundary)	US-PGPUB; USPAT; DERWENT	OR	OFF	2008/09/17 16:51
S64	3	S52 and (address near3 table)	US-PGPUB; USPAT; DERWENT	OR	OFF	2008/09/17 16:51
S65	3	S52 and (boundary)	US-PGPUB; USPAT; DERWENT	OR	OFF	2008/09/17 16:52
S66	1	2001-273151.NRAN.	DERWENT	OR	OFF	2008/09/17 18:48
S67	1	2001-273151.NRAN.	DERWENT	OR	OFF	2008/09/17 18:48
S68	147711	(memory smart plastic IC) near3 card	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:12
S69	18725	S68 and (((divided protected secure portion) near3 memory)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:12
S70	3391	S69 and boundary	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:13
S71	834	S70 and (address near3 table)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:13
S72	321	S71 and @ad<"20021216"	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:13
S73	1737	S68 and (((divided portion) and (protected secure)) near3 memory)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:15
S74	548	S73 and boundary	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:16
S75	268	S74 and (address near3 table)	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:16

S76	91	S75 and @ad<"20021216"	US-PGPUB; USPAT; USOCR	OR	ON	2008/09/17 19:16
-----	----	------------------------	---------------------------	----	----	---------------------

9/18/2008 10:04:19 AM

C:\Documents and Settings\kshepelev\My Documents\EAST\Workspaces\10539164 memory  
device.wsp